



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SK4198FS — N-Channel Silicon MOSFET — General-Purpose Switching Device Applications

Features

- ON-resistance $R_{DS(on)}=1.8\Omega$ (typ.)
- 10V drive
- Input capacitance $C_{iss}=360pF$ (typ.)
- Repetitive avalanche guarantee

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		600	V
Gate-to-Source Voltage	V_{GSS}		± 30	V
Drain Current (DC)	I_{Dc} *1	Limited only by maximum temperature $T_{ch}=150^\circ C$	5	A
	I_{Dpack} *2	$T_c=25^\circ C$ (SANYO's ideal heat dissipation condition)*3	4	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	18	A
Allowable Power Dissipation	P_D		2.0	W
		$T_c=25^\circ C$ (SANYO's ideal heat dissipation condition)*3	30	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$
Avalanche Energy (Single Pulse) *4	E_{AS}		55	mJ
Avalanche Current *5	I_{AV}		4.5	A
Avalanche Energy (Repetition)	E_{AR}	Limited only by maximum temperature $T_{ch}=150^\circ C$	3	mJ

Note : *1 Shows chip capability.

*2 Package limited.

*3 SANYO's condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

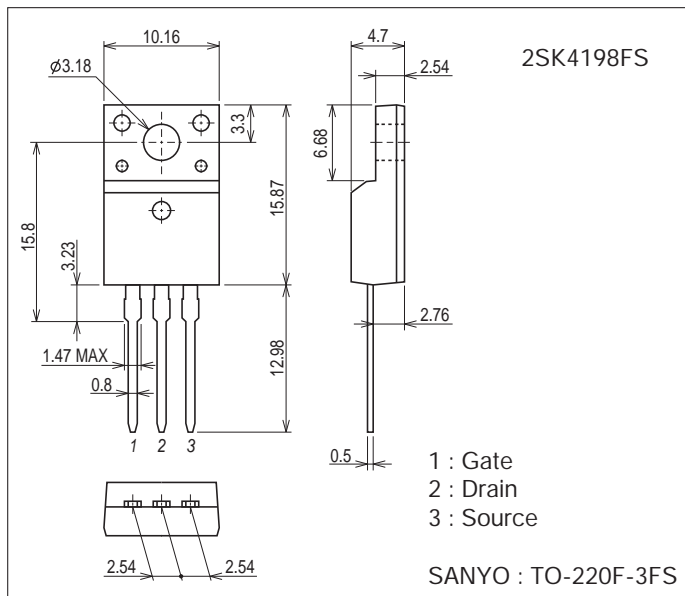
*4 $V_{DD}=50V$, $L=5mH$, $I_{AV}=4.5A$ (Fig.1)

*5 $L \leq 5mH$, Single pulse

Package Dimensions

unit : mm (typ)

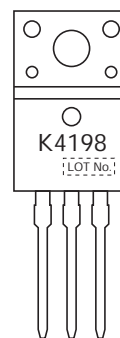
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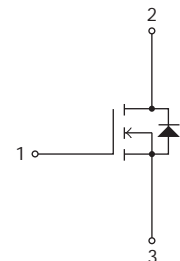
Product & Package Information

- Package : TO-220F-3FS
- JEITA, JEDEC : SC-67
- Minimum Packing Quantity : 50 pcs./magazine

Marking



Electrical Connection



SANYO Semiconductor Co., Ltd.

<http://www.sanyosemi.com/en/network/>

2SK4198FS

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
			min	typ	max		
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=10mA, VGS=0V	600			V	
Zero-Gate Voltage Drain Current	IDSS	VDS=480V, VGS=0V			100	μA	
Gate-to-Source Leakage Current	IGSS	VGS=±30V, VDS=0V			±100	nA	
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	3		5	V	
Forward Transfer Admittance	yfs	VDS=10V, ID=2.5A	1.2	2.4		S	
Static Drain-to-Source On-State Resistance	RDS(on)	ID=2.5A, VGS=10V		1.8	2.34	Ω	
Input Capacitance	Ciss	VDS=30V, f=1MHz		360		pF	
Output Capacitance	Coss				69		pF
Reverse Transfer Capacitance	Crss				15		pF
Turn-ON Delay Time	td(on)	See Fig.2		13		ns	
Rise Time	tr				28		ns
Turn-OFF Delay Time	td(off)				39		ns
Fall Time	tf				15		ns
Total Gate Charge	Qg	VDS=200V, VGS=10V, ID=5A		14.3		nC	
Gate-to-Source Charge	Qgs				3.0		nC
Gate-to-Drain "Miller" Charge	Qgd				8.2		nC
Diode Forward Voltage	VSD	IS=5A, VGS=0V		0.9	1.2	V	

Fig.1 Unclamped Inductive Switching Test Circuit

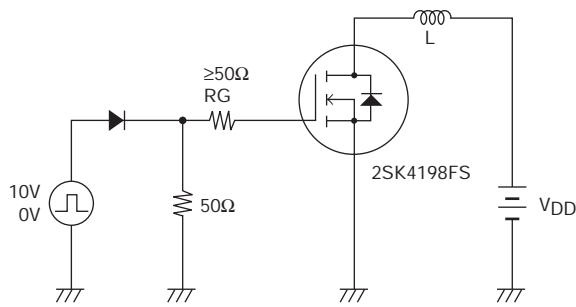
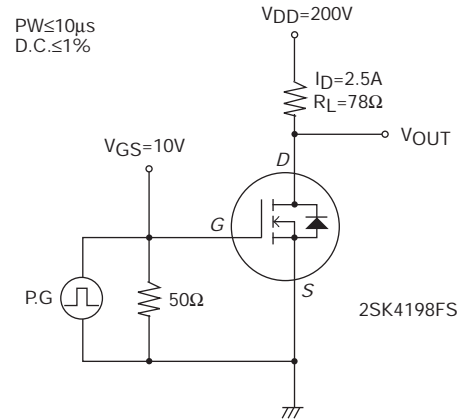


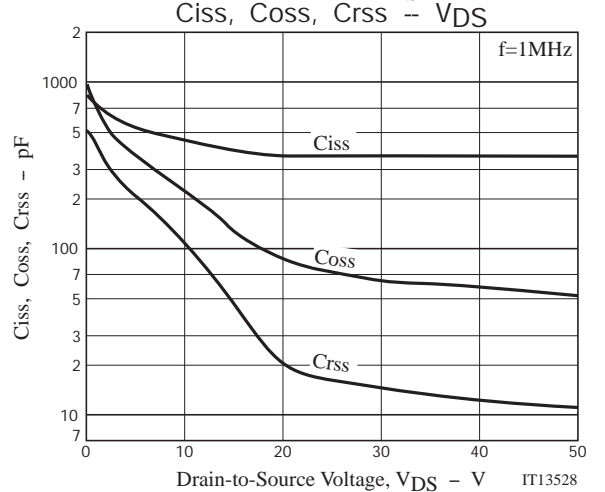
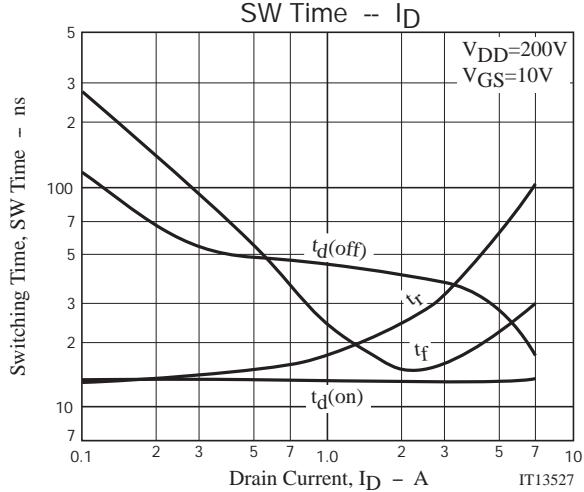
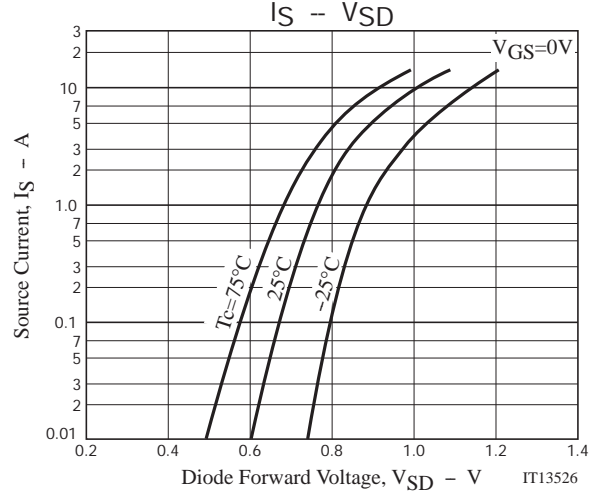
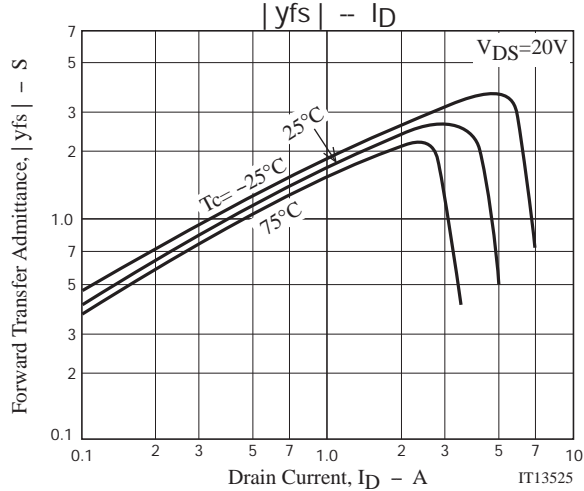
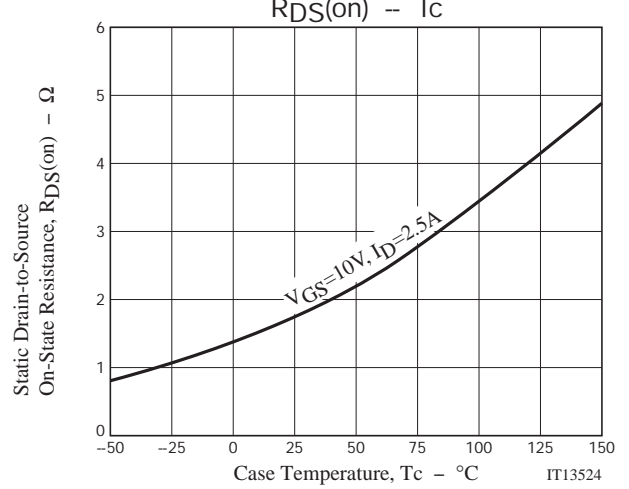
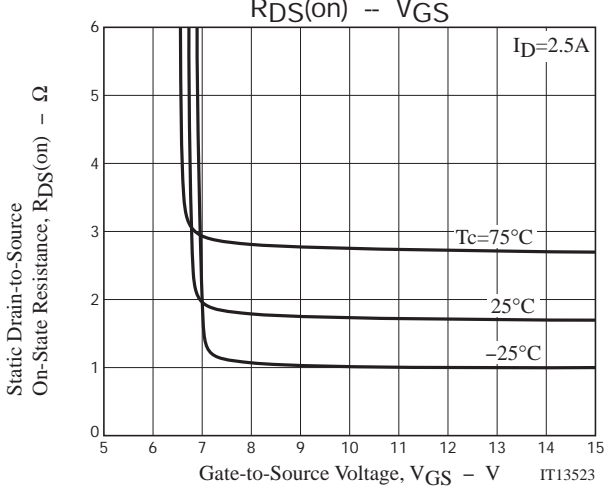
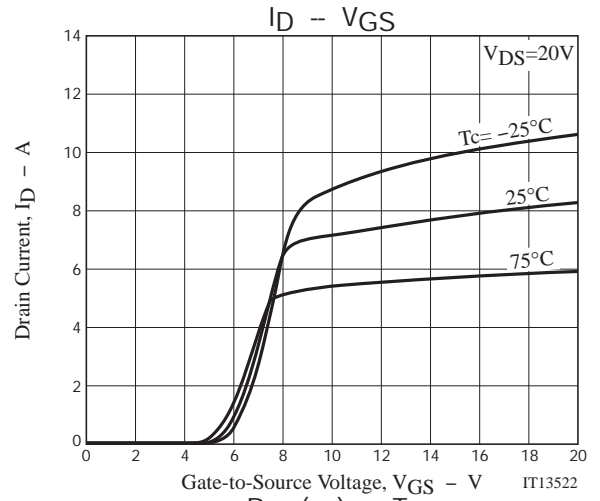
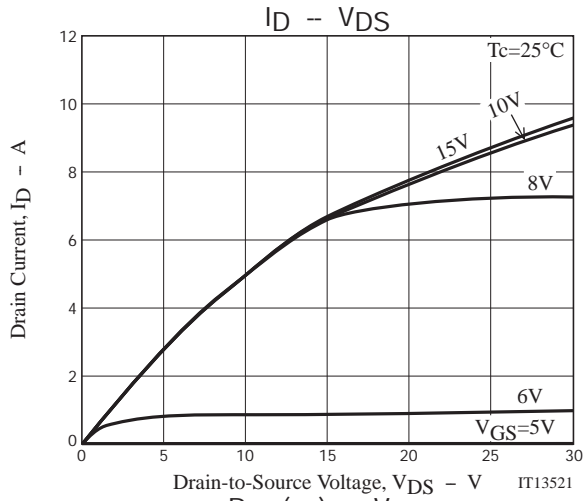
Fig.2 Switching Time Test Circuit



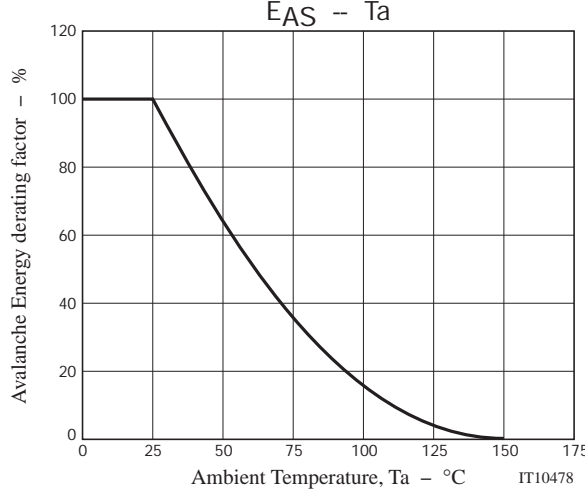
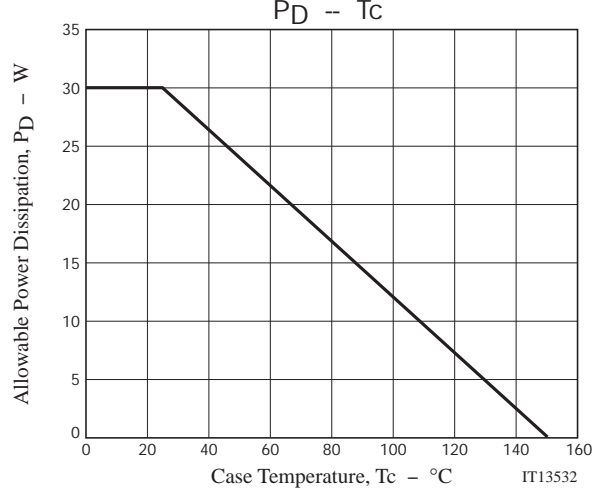
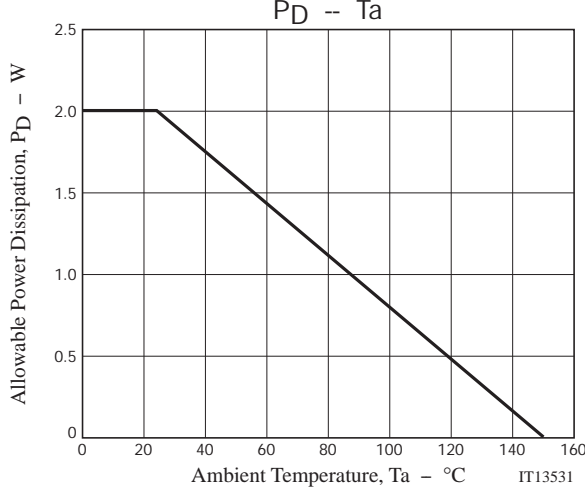
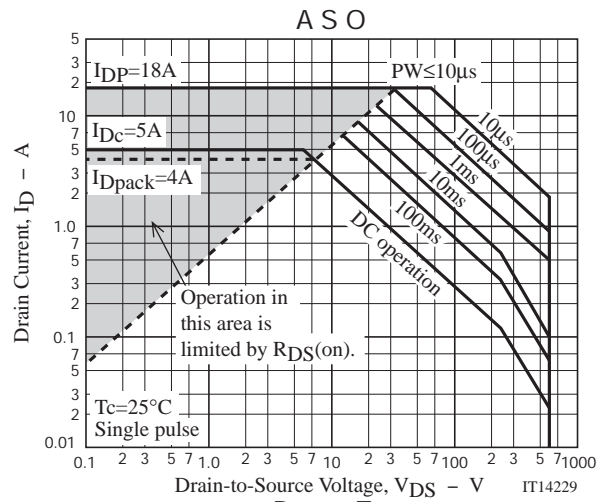
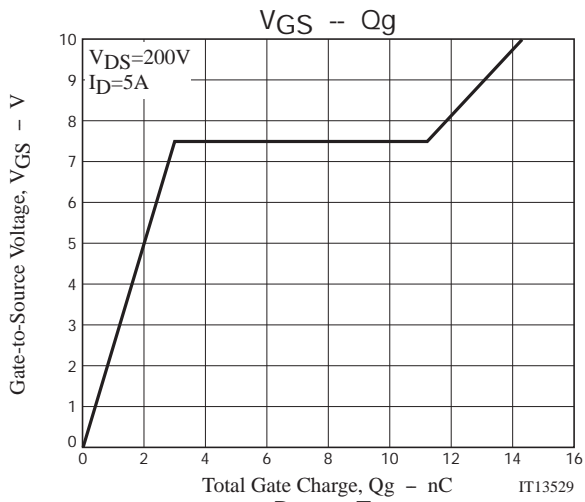
Ordering Information

Device	Package	Shipping	memo
2SK4198FS	TO-220F-3FS	50pcs./magazine	Pb Free

2SK4198FS



2SK4198FS



2SK4198FS

Magazine Specification

2SK4198FS

1. Packing Format

Package Name	Magazine Name	Maximum Number of devices contained (pcs)			Packing format	
		Magazine	Inner box	Outer box	Inner BOX	Outer BOX
TO-220F-3FS	TO-220F	50	1,000	4,000	SPD-0V0001 20 magazines contained Dimensions:mm (external) 568×150×55	SPT-081029 4 inner boxes contained Dimensions:mm (external) 590×225×178

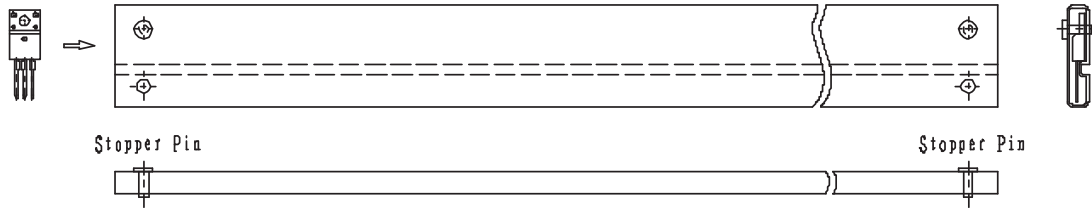
2. Magazine dimensions

(unit:mm)

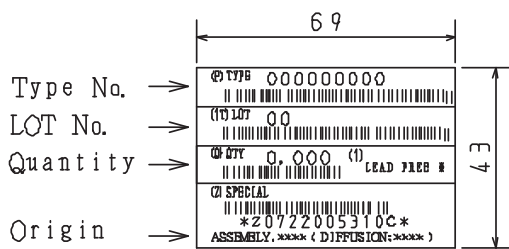


Tolerance=±0.3mm
 Thickness=0.7±0.2mm
 Length =532.5±2mm
 Material =PVC (Antistatic treatment)

3. Storage method to magazine



4. Inner box label (unit:mm)



5. Outer box label (unit:mm)

It is a label at the time of factory shipments.
 The form of a label may change in physical
 distribution process.



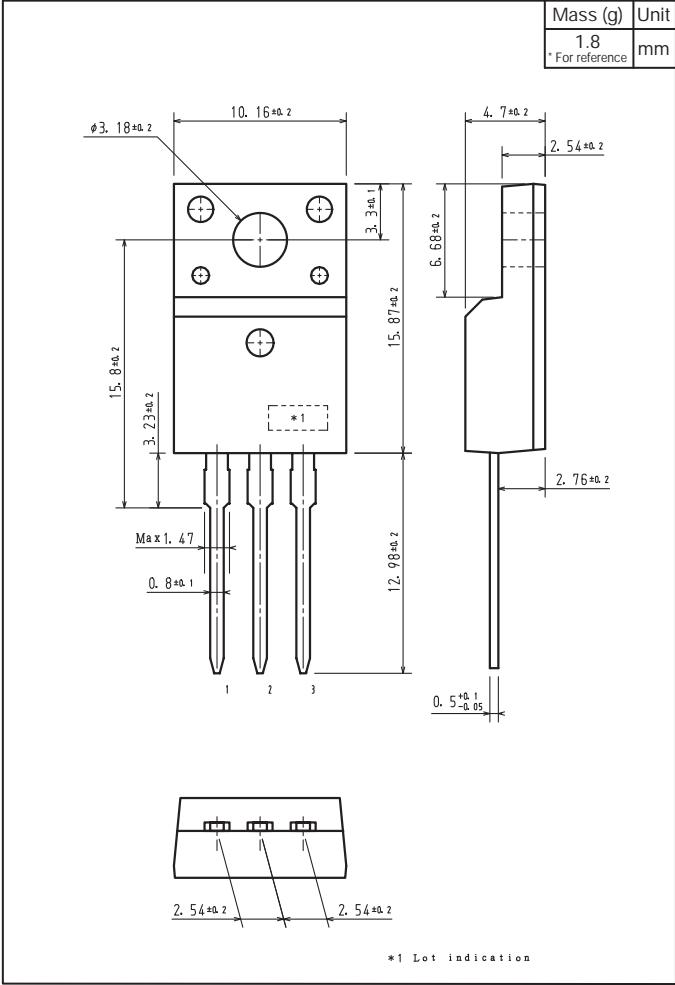
NOTE (1)

The LEAD FREE # description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A

2SK4198FS

Outline Drawing
2SK4198FS



Note on usage : Since the 2SK4198FS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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